

## TO-92 Plastic-Encapsulate Transistors

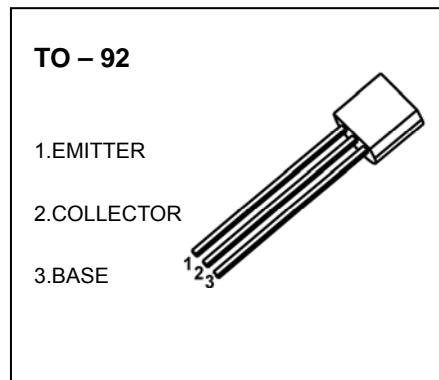
### **8550SS TRANSISTOR (PNP)**

#### **FEATURES**

- General Purpose Switching and Amplification.

#### **MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$ unless otherwise noted)**

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	-40	V
$V_{CEO}$	Collector-Emitter Voltage	-25	V
$V_{EBO}$	Emitter-Base Voltage	-5	V
$I_C$	Collector Current -Continuous	-1.5	A
$P_c$	Collector Power Dissipation	1	W
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	125	$^\circ\text{C}/\text{W}$
$T_j$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~+150	$^\circ\text{C}$



#### **ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ\text{C}$ unless otherwise specified)**

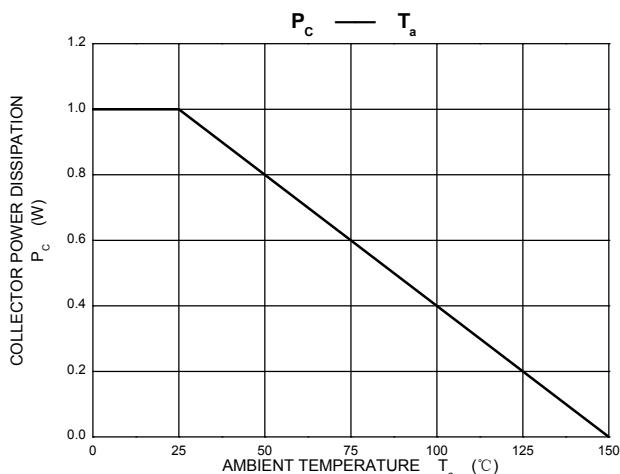
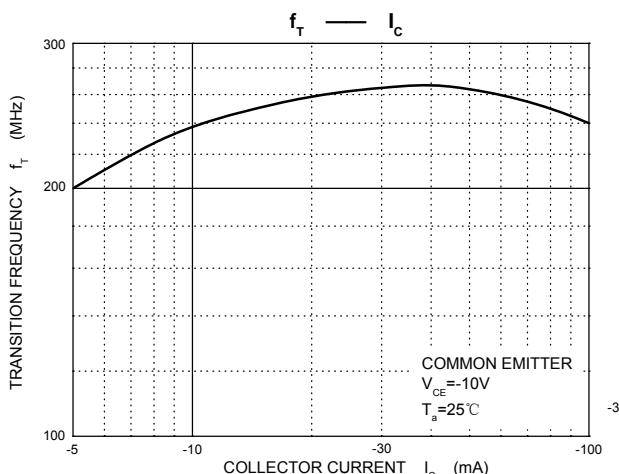
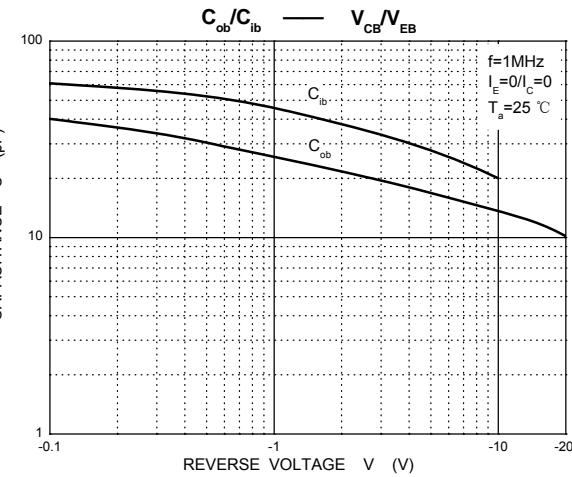
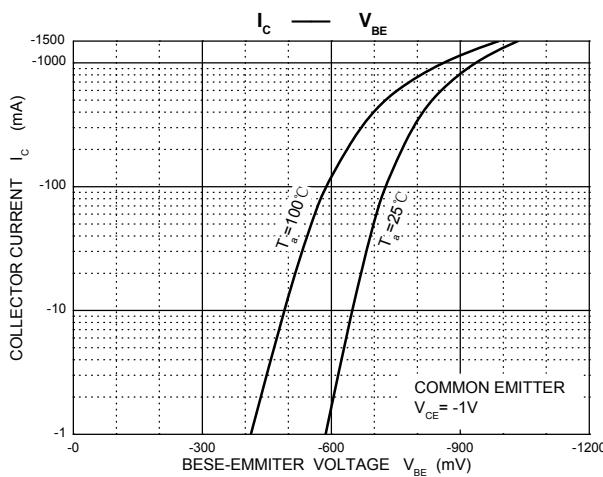
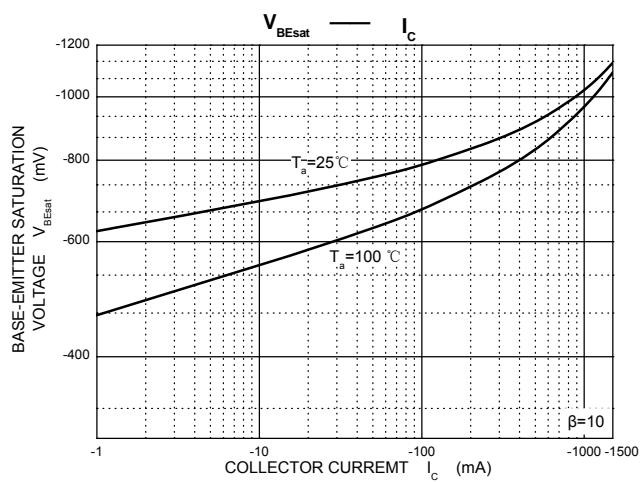
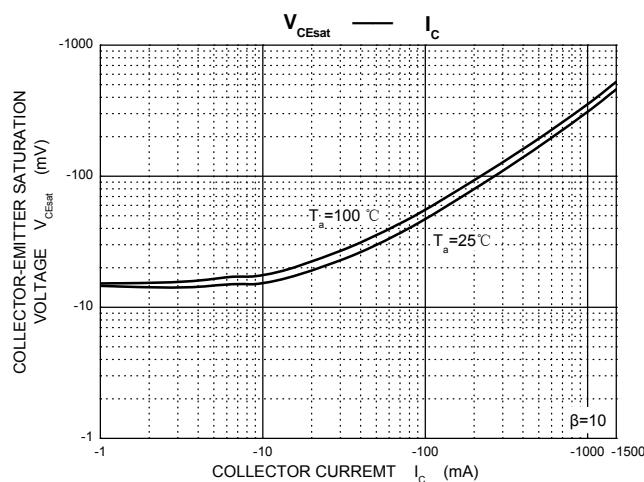
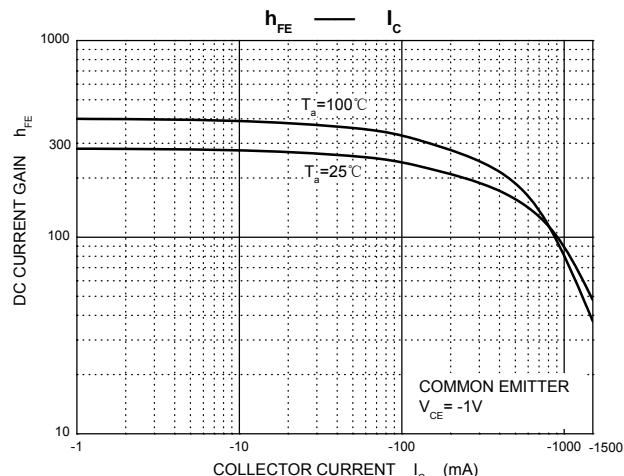
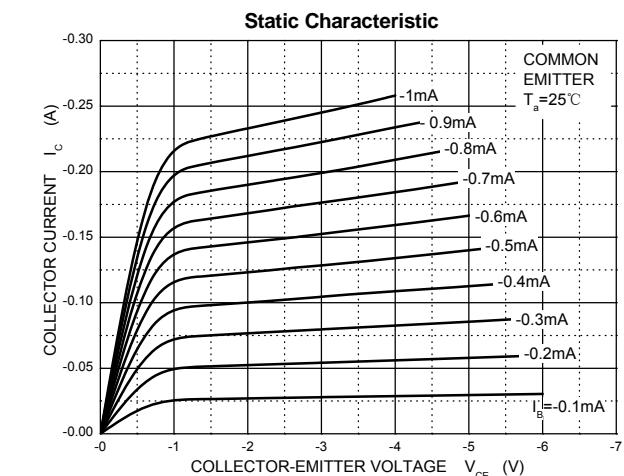
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = -0.1\text{mA}, I_E = 0$	-40			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -0.1\text{mA}, I_B = 0$	-25			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -0.1\text{mA}, I_C = 0$	-5			V
Collector cut-off current	$I_{CBO}$	$V_{CB} = -40\text{V}, I_E = 0$			-0.1	$\mu\text{A}$
Collector cut-off current	$I_{CEO}$	$V_{CE} = -20\text{V}, I_B = 0$			-0.1	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB} = -5\text{V}, I_C = 0$			-0.1	$\mu\text{A}$
DC current gain	$h_{FE(1)}$	$V_{CE} = -1, I_C = -100\text{mA}$	85		300	
	$h_{FE(2)}$	$V_{CE} = -1\text{V}, I_C = -800\text{mA}$	40			
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$	$I_C = -800\text{mA}, I_B = -80\text{mA}$			-0.5	V
Base-emitter saturation voltage	$V_{BE(\text{sat})}$	$I_C = -800\text{mA}, I_B = -80\text{mA}$			-1.2	V
Transition frequency	$f_T$	$V_{CE} = -10\text{V}, I_C = -50\text{mA}, f = 30\text{MHz}$	100			MHz

#### **CLASSIFICATION OF $h_{FE(1)}$**

RANK	B	C	D
RANGE	85-160	120-200	160-300

# Typical Characteristics

8550SS



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